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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





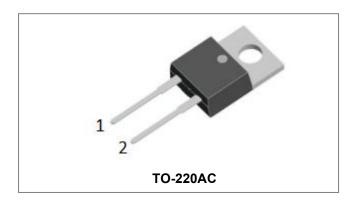








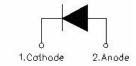
# **MBR20200 SCHOTTKY RECTIFIER**



#### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=133°C, rectangular wave form	20	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	230	Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 20A, Pulse, T <sub>J</sub> = 25 °C	0.89	0.95	V
	V <sub>F2</sub>	@ 20A, Pulse, T <sub>J</sub> = 125 °C	0.75	0.80	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.001	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	0.1	6.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz$	200	400	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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# Thermal-Mechanical Specifications:

Characteristics	Symbol Condition		Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	2.0	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0</sub> CS	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

# **Ratings and Characteristics Curves**

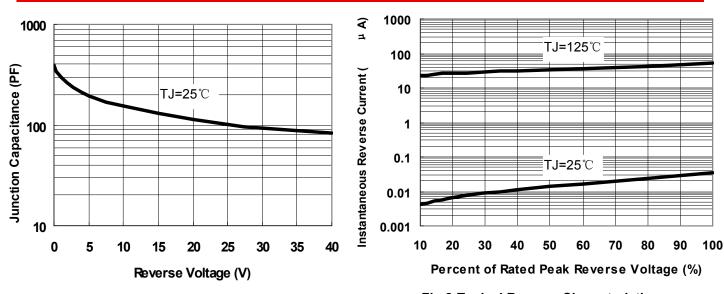


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

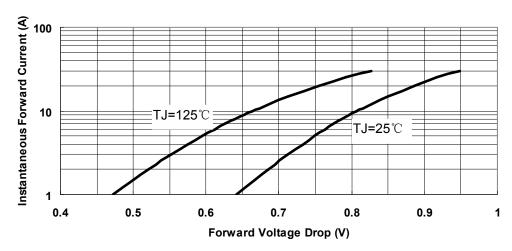


Fig.3-Typical Instantaneous Forward Voltage Characteristics

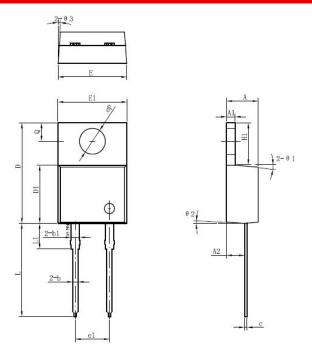
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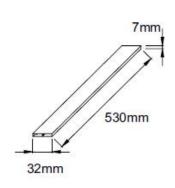


#### **Mechanical Dimensions TO-220AC**



Symbol	Dimensions in millimeters			
-	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.50	8.07	8.90	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1	4.98	5.08	5.18	
H1	6.04	6.24	6.44	
L	13.00	13.86	14.08	
L1	3.56	3.80	3.96	
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		5°		
Θ2		4°		
Θ3		4°		

# **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 20 = Forward Current (20A) 200 = Reverse Voltage(200V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
MBR20200	TO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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